

Asymmetric Supercapacitors with High Energy Densities

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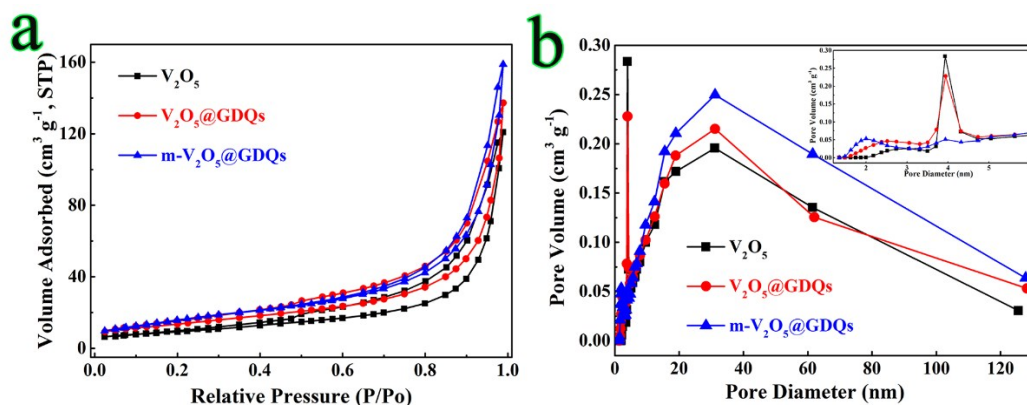


Fig. S1 (a) Nitrogen adsorption–desorption isotherms and (b) pore size distribution curves of V_2O_5 , $V_2O_5@GDQs$, and $m-V_2O_5@GDQs$

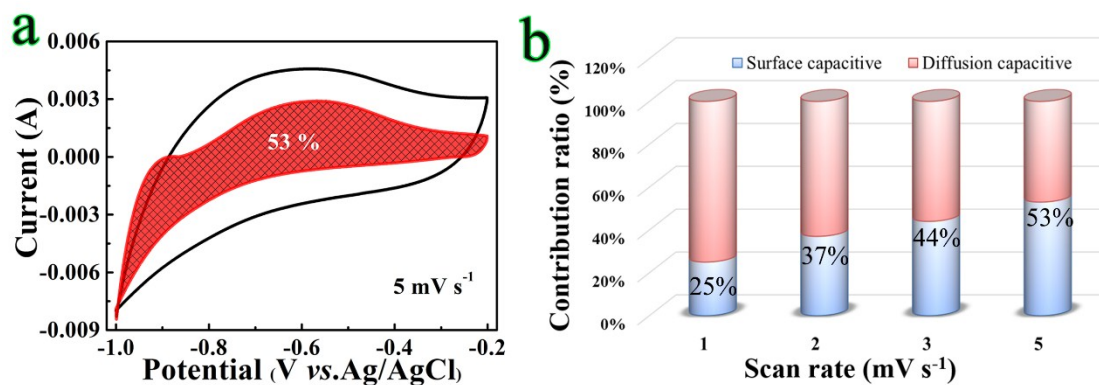


Fig. S2 (a) Separation of the capacitive (shaded region) and diffusion currents in the m-V₂O₅@GQDs at a scan rate of 5 mVs⁻¹. (b) Contribution ratio of the diffusion-controlled and capacitance-controlled charges at different scan rates.

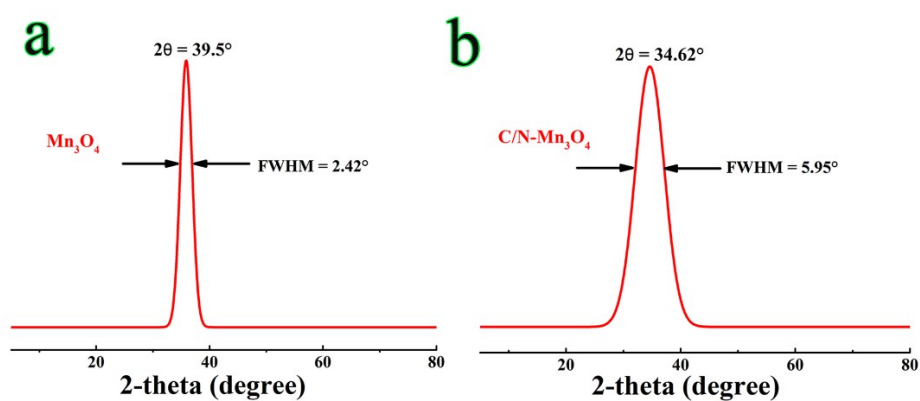


Fig. S3 The curves show full width at half maximum (FWHM) of (a) Mn_3O_4 and (b) $\text{C/N-Mn}_3\text{O}_4$.

Table S1. Comparison of the specific capacitance of other V₂O₅-based supercapacitor.

Preparation method	Potential window	Electrolyte	Current density	Specific capacitance	Ref.
m-V ₂ O ₅ @ GQDs	-1 to -0.2 V	1M Li ₂ SO ₄	2 A g ⁻¹	761 F g ⁻¹	This
rGO/V ₂ O ₅	-0.8 to 0.8 V -	1 M LiClO ₄ /PC	0.1 A g ⁻¹	384 F g ⁻¹	23
V ₂ O ₅ @PPy	0.4 to 0.5 V	1M Na ₂ SO ₄	0.2 A g ⁻¹	334 F g ⁻¹	39
N-GA@V ₂ O ₅ NWAs	-0.3 to 0.7 V	8 M LiCl	0.5 A g ⁻¹	710 F g ⁻¹	40
V ₂ O ₅	-0.2 to 0.6 V	1M Na ₂ SO ₄	2 mV s ⁻¹	256 F g ⁻¹	41
N-CNFs/V ₂ O ₅	-0.1 to 1 V	1M Na ₂ SO ₄	0.5 A g ⁻¹	595.1 F g ⁻¹	42